

NCE N-Channel Enhancement Mode Power MOSFET

Description

The NCE8295A uses advanced trench technology and design to provide excellent $R_{DS(ON)}$ with low gate charge. This device is suitable for use in PWM, load switching and general purpose applications.

General Features

• $V_{DS} = 82V, I_D = 95A$ $R_{DS(ON)} < 8.0 \text{ m}\Omega @ V_{GS} = 10V \text{ (Typ:6.6m}\Omega)$

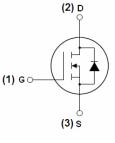
- High density cell design for ultra low Rdson
- Fully characterized avalanche voltage and current
- Special designed for convertors and power controls
- Good stability and uniformity with high E_{AS}
- Excellent package for good heat dissipation
- Special process technology for high ESD capability

Application

- Power switching application
- Hard switched and High frequency circuits
- Uninterruptible power supply

100% UIS TESTED!

100% ΔVds TESTED!



Schematic diagram



Marking and pin assignment



Package Marking and Ordering Information

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
NCE8295A	NCE8295A	TO-220-3L	-	-	-

Absolute Maximum Ratings (T_A=25 ℃unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	V _{DS}	82	V
Gate-Source Voltage	V _{GS}	±20	V
Drain Current-Continuous	I _D	95	А
Drain Current-Continuous(T _C =100 °C)	I _D (100℃)	67	Α
Pulsed Drain Current	I _{DM}	320	А
Maximum Power Dissipation	P _D	170	W
Derating factor		1.13	W/℃
Single pulse avalanche energy (Note 5)	E _{AS}	529	mJ
Operating Junction and Storage Temperature Range	T_{J} , T_{STG}	-55 To 175	$^{\circ}$ C



Thermal Characteristic

Thermal Resistance, Junction-to-Case ^(Note 2)	R _{eJC}	0.88	°C/W	Ì
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Electrical Characteristics (T_A=25°C unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics	<u> </u>		•			
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V I _D =250μA	82	-	-	V
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =82V,V _{GS} =0V	-	-	1	μΑ
Gate-Body Leakage Current	I _{GSS}	V _{GS} =±20V,V _{DS} =0V	-	-	±100	nA
On Characteristics (Note 3)	<u> </u>		•			•
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}$, $I_{D}=250\mu A$	2	2.9	4	V
Drain-Source On-State Resistance	R _{DS(ON)}	V _{GS} =10V, I _D =20A	-	6.6	8.0	mΩ
Forward Transconductance	g FS	V_{DS} =5 V , I_D =20 A	-	50	-	S
Dynamic Characteristics (Note4)	<u> </u>		•			
Input Capacitance	C _{lss}	\/ -40\/\/ -0\/	-	5633	-	PF
Output Capacitance	Coss	V_{DS} =40V, V_{GS} =0V,	-	268	-	PF
Reverse Transfer Capacitance	C _{rss}	F=1.0MHz	-	226	-	PF
Switching Characteristics (Note 4)	<u> </u>		•			•
Turn-on Delay Time	t _{d(on)}		-	18	-	nS
Turn-on Rise Time	t _r	V_{DD} =40V, R_L =15 Ω R_G =2.5 Ω , V_{GS} =10V	-	12	-	nS
Turn-Off Delay Time	t _{d(off)}		-	56	-	nS
Turn-Off Fall Time	t _f		-	15	-	nS
Total Gate Charge	Qg	\/ 40\/ 50A	-	109.3	-	nC
Gate-Source Charge	Q _{gs}	$V_{DS}=40V, I_{D}=50A,$	-	35.1	-	nC
Gate-Drain Charge	Q_{gd}	V _{GS} =10V	-	25.8	-	nC
Drain-Source Diode Characteristics	<u> </u>		•			•
Diode Forward Voltage (Note 3)	V _{SD}	V _{GS} =0V,I _S =95A	-	-	1.2	V
Diode Forward Current (Note 2)	Is		-	-	95	Α
Reverse Recovery Time	t _{rr}	Tj=25°C,I _F =100A	-		37	nS
Reverse Recovery Charge	Qrr	di/dt=100A/µs ^(Note3)	-		58	nC

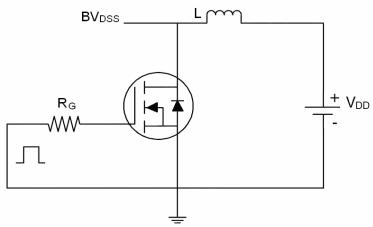
Notes:

- 1. Repetitive Rating: Pulse width limited by maximum junction temperature.
- 2. Surface Mounted on FR4 Board, t ≤ 10 sec.
- **3.** Pulse Test: Pulse Width ≤ 300μ s, Duty Cycle ≤ 2%.
- 4. Guaranteed by design, not subject to production
- 5. EAS condition: Tj=25 $^{\circ}\text{C}$,VDD=40V,VG=10V,L=0.5mH,Rg=25 Ω

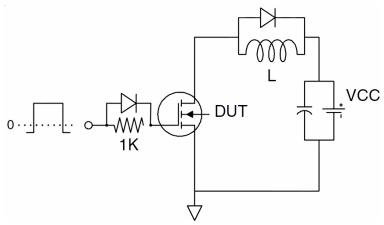


Test Circuit

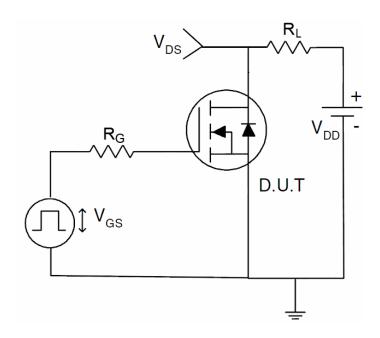
1) E_{AS} Test Circuits



2) Gate Charge Test Circuit



3) Switch Time Test Circuit





Typical Electrical and Thermal Characteristics (Curves

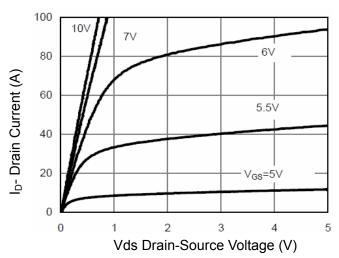


Figure 1 Output Characteristics

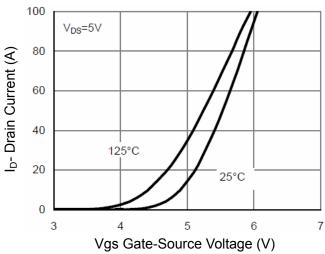


Figure 2 Transfer Characteristics

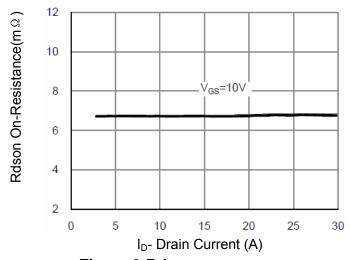


Figure 3 Rdson- Drain Current

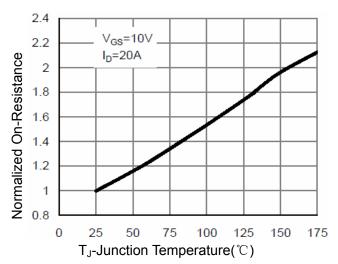


Figure 4 Rdson-Junction Temperature

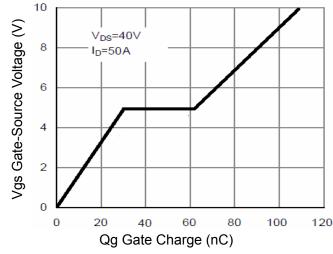


Figure 5 Gate Charge

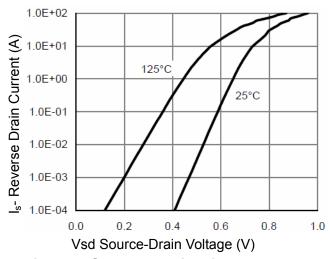
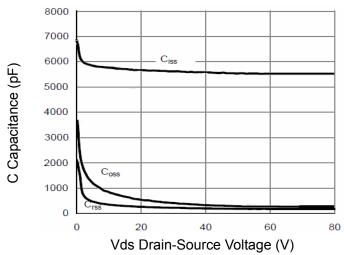


Figure 6 Source- Drain Diode Forward

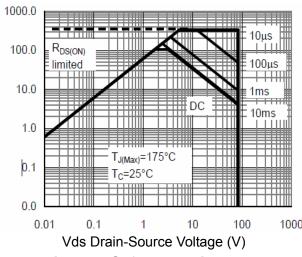




240 200 160 120 80 40 0 25 50 75 100 125 150 175 T_J-Junction Temperature(°C)

Figure 7 Capacitance vs Vds

Figure 9 Power De-rating



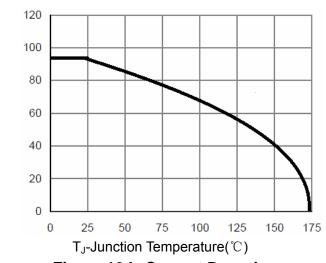
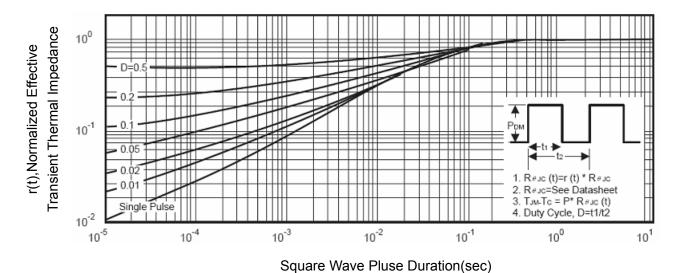


Figure 8 Safe Operation Area

Figure 10 ID Current De-ratin

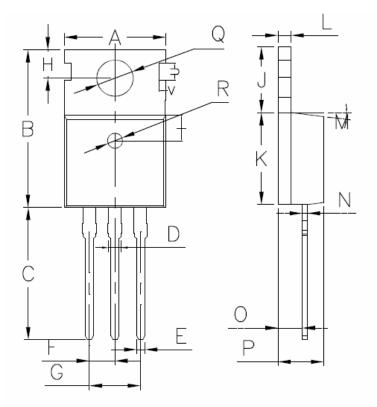


D- Drain Current (A)

Figure 11 Normalized Maximum Transient Thermal Impedance



TO-220 Package Information



Symbol		Non	Max
A	9.80	10.00	10.20
В	15.40	15.60	15.80
С	15. 40 13. 02	13.37	13.72
D	1. 18 0. 70 2. 42 4. 84 2. 73 2. 40 6. 40	1.31	1.44
Е	0.70	0.80	0.90
F	2.42	2.54	2.66
G	4.84	5.08	5. 32
Н	2.73	2.80	2.87
Ι	2.40	2.50	2.60
J	6.40	6.50	6.60
K	9.00	9.10	9. 20
L	1. 29	1.30	1.32
M	1. 29 6. 5° 0. 48 2. 35	7.0°	7.5°
N	0.48	0.50	0.56
0	2.35	2.4	2.5
P	4.4	4. 5	4.7
A B C D E F G H I J K L M N O P Q R S U V	9. 00 1. 29 6. 5° 0. 48 2. 35 4. 4 3. 5 1. 3	1. 31 0. 80 2. 54 5. 08 2. 80 2. 50 6. 50 9. 10 1. 30 7. 0° 0. 50 2. 4 4. 5 3. 6 1. 4 2. 5° 1. 75 0. 68	1. 44 0. 90 2. 66 5. 32 2. 87 2. 60 6. 60 9. 20 1. 32 7. 5° 0. 56 2. 5 4. 7 3. 7 1. 5
R	1.3	1.4	1.5
S	2°	2.5°	3°
U	1.65	1.75	1.85
V	0.58	0.68	0.78



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